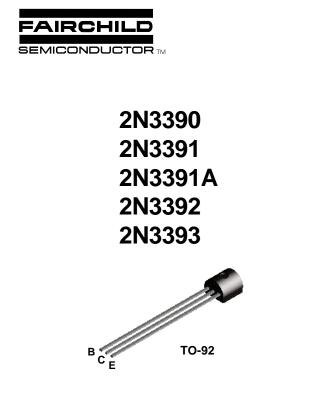
Discrete POWER & Signal **Technologies**



NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100A for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	25	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	500	mA
TJ, Tsta	Operating and Storage Junction Temperature Range	-55 to +150	۰C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах	Units
		2N3390 / 3391/A / 3392 / 3393	
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
R _{0JC}	Thermal Resistance, Junction to Case	83.3	°C/W
R _{0JA}	Thermal Resistance, Junction to Ambient	200	°C/W

NPN General Purpose Amplifier (continued)

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Symbol	Parameter	Test Conditions	Min	Max	Units
	RACTERISTICS			1	
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	25		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 10 \ \mu A, I_{E} = 0$	25		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \ \mu A, \ I_C = 0$	5.0		V
I _{CBO}	Collector-Cutoff Current	$V_{CB} = 18 \text{ V}, I_E = 0$		100	nA
I _{EBO}	Emitter-Cutoff Current	$V_{EB} = 5.0 \text{ V}, I_{C} = 0$		100	nA
	RACTERISTICS*	V _{CE} = 4.5 V, I _C = 2.0 mA		1	T

SMALL SIGNAL CHARACTERISTICS

C _{ob}	Output Capacitance	V _{CB} = 10 V, f = 1.0 MHz	2.0	10	pF
h _{fe}	Small-Signal Current Gain	$\label{eq:loss} \begin{array}{l} I_{C} = 2.0 \text{ mA}, \ V_{CE} = 4.5 \text{ V}, \\ f = 1.0 \text{ kHz} & \textbf{2N3390} \\ & \textbf{2N3391/A} \\ & \textbf{2N3392} \\ & \textbf{2N3393} \end{array}$	400 250 150 90	1250 800 500 400	
NF	Noise Figure			5.0	dB

*Pulse Test: Pulse Width $\leq 300~\mu\text{s},~\text{Duty}~\text{Cycle} \leq 2.0\%$

2N3390 / 2N3391 / 2N3391A / 2N3392 / 2N3393



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